

Vishay Semiconductors

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High Performance Schottky Rectifier, 2 x 15 A



| PRIMARY CHARACTERISTICS | | | | | |
|----------------------------------|-----------------|--|--|--|--|
| I _{F(AV)} | 2 x 15 A | | | | |
| V _R | 25 V, 30 V | | | | |
| V _F at I _F | 0.40 V | | | | |
| I _{RM} typ. | 97 mA at 125 °C | | | | |
| T _J max. | 150 °C | | | | |
| E _{AS} | 13 mJ | | | | |
| Package | TO-220AB 3L | | | | |
| Circuit configuration | Common cathode | | | | |

FEATURES

- 150 °C T_J operation
- Low forward voltage drop
- High frequency operation



COMPLIANT

- HALOGEN High purity, high temperature epoxy FREE encapsulation for enhanced mechanical strength and moisture resistance
- · Guard ring for enhanced ruggedness and long term reliability
- Designed and qualified according to JEDEC[®]-JESD 47
- · Material categorization: for definitions of compliance please see www.vishay.com/doc?99912

DESCRIPTION

The VS-32CTQ... Schottky rectifier series has been optimized for low reverse leakage at high temperature. The proprietary barrier technology allows for reliable operation up to 150 °C junction temperature. Typical applications are in switching power supplies, converters, freewheeling diodes, and reverse battery protection.

| MAJOR RATINGS AND CHARACTERISTICS | | | | | |
|-------------------------------------|--|-------------|----|--|--|
| SYMBOL CHARACTERISTICS VALUES UNITS | | | | | |
| I _{F(AV)} | Rectangular waveform | 30 | Α | | |
| V _{RRM} | | 25/30 | V | | |
| I _{FSM} | t _p = 5 μs sine | 900 | А | | |
| V _F | 15 A _{pk} , T _J = 125 °C | 0.40 | V | | |
| TJ | Range | -55 to +150 | °C | | |

| VOLTAGE RATINGS | | | | |
|--------------------------------------|------------------|----------------|----------------|-------|
| PARAMETER | SYMBOL | VS-32CTQ025-M3 | VS-32CTQ030-M3 | UNITS |
| Maximum DC reverse voltage | V _R | 25 | 30 | V |
| Maximum working peak reverse voltage | V _{RWM} | 25 | 30 | v |

| ABSOLUTE MAXIMUM RATINGS | | | | | | |
|---|--------------------|---|---|-------|----|--|
| PARAMETER | SYMBOL | TEST COND | VALUES | UNITS | | |
| Maximum average forward current, see fig. 5 | I _{F(AV)} | 50 % duty cycle at T_{C} = 115 °C, rectangular waveform | | 30 | | |
| Maximum peak one cycle non-repetitive | | 5 μs sine or 3 μs rect. pulse | Following any rated load | 900 | A | |
| surge current, see fig. 7 | I _{FSM} | 10 ms sine or 6 ms rect. pulse | condition and with rated V _{RRM} applied | 250 | | |
| Non-repetitive avalanche energy | E _{AS} | T _J = 25 °C, I _{AS} = 1.20 A, L = 11.10 mH | | 13 | mJ | |
| Repetitive avalanche current | I _{AR} | $\begin{array}{c} \mbox{Current decaying linearly to zero in 1 } \mu s \\ \mbox{Frequency limited by } T_J \mbox{ maximum } V_A = 1.5 \ x \ V_R \ typical \end{array} \qquad 3$ | | А | | |

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| ELECTRICAL SPECIFICATIONS | | | | | | |
|--------------------------------------|--------------------------------|---|---------------------------------------|-------|------|--|
| PARAMETER | SYMBOL | TEST CO | VALUES | UNITS | | |
| | | 15 A | T _{.1} = 25 °C | 0.49 | V | |
| Maximum forward voltage drop | V _{FM} ⁽¹⁾ | 30 A | 1j=25 C | 0.58 | | |
| See fig. 1 | VFM (*) | 15 A | T _{.1} = 125 °C | 0.40 | | |
| | | 30 A | 1) = 125 0 | 0.53 | | |
| Maximum reverse leakage current | I _{RM} ⁽¹⁾ | T _J = 25 °C | $V_{\rm B}$ = Rated $V_{\rm B}$ | 1.75 | mA | |
| | | T _J = 125 °C | V _R = naleu V _R | 145 | | |
| Typical reverse leakage current | I _{RM} ⁽¹⁾ | $T_J = 125 \text{ °C}$ $V_R = \text{Rated } V_R$ | | 97 | mA | |
| Threshold voltage | V _{F(TO)} | | 0.233 | V | | |
| Forward slope resistance | r _t | $T_J = T_J maximum$ | | 9.09 | mΩ | |
| Maximum junction capacitance per leg | CT | $V_R = 5 V_{DC}$ (test signal range 100 kHz to 1 MHz) 25 °C | | 1300 | pF | |
| Typical series inductance per leg | LS | Measured lead to lead 5 m | 8.0 | nH | | |
| Maximum voltage rate of change | dV/dt | Rated V _R 10 000 V/ | | | V/µs | |

Note

 $^{(1)}\,$ Pulse width < 300 $\mu s,$ duty cycle < 2 %

| THERMAL - MECHANICAL SPECIFICATIONS | | | | | | | |
|---|---------|-----------------------------------|--------------------------------------|------------|------------|--|--|
| PARAMETER | | SYMBOL | TEST CONDITIONS | VALUES | UNITS | | |
| Maximum junction and stor temperature range | age | T _J , T _{Stg} | | -55 to 150 | °C | | |
| Maximum thermal resistance junction to case per leg | ce, | R _{thJC} | DC operation See fig. 4 | 3.25 | °C/W | | |
| Typical thermal resistance, case to heatsink | | R _{thCS} | Mounting surface, smooth and greased | 0.50 | 0/11 | | |
| Approximate weight | | | | 2 | g | | |
| Approximate weight | | | | 0.07 | oz. | | |
| Mounting torque | minimum | | | 6 (5) | kgf ⋅ cm | | |
| Mounting torque - | maximum | | | 12 (10) | (lbf ⋅ in) | | |
| | | | | | Q025 | | |
| Marking device | | | Case style TO-220AB 3L | 32CT | Q030 | | |



VS-32CTQ025-M3, VS-32CTQ030-M3

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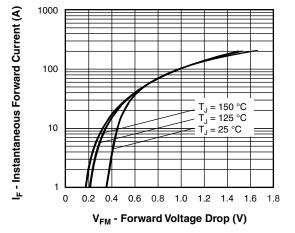


Fig. 1 - Maximum Forward Voltage Drop Characteristics

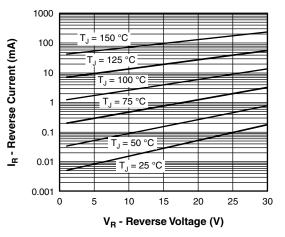


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage

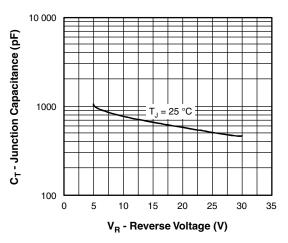


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

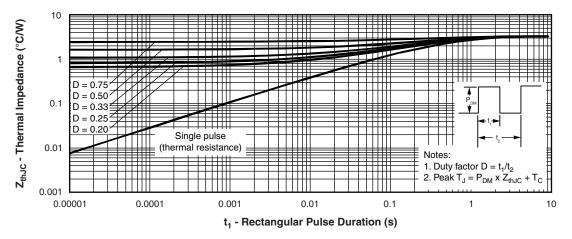
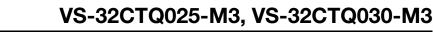


Fig. 4 - Maximum Thermal Impedance ZthJC Characteristics

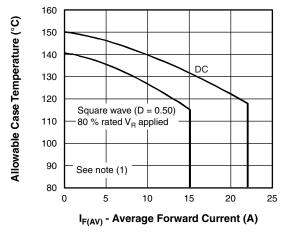
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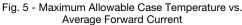
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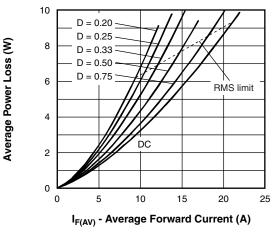


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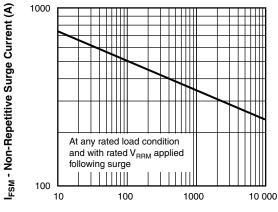
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t_p - Square Wave Pulse Duration (μs)

Fig. 7 - Maximum Non-Repetitive Surge Current

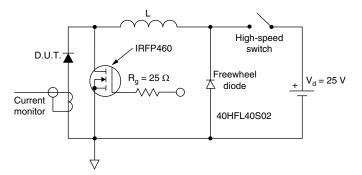


Fig. 8 - Unclamped Inductive Test Circuit

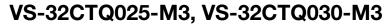
Note

 Pd_{REV} = inverse power loss = $V_{R1} \times I_R (1 - D)$; I_R at V_{R1} = 80 % rated V_R

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ORDERING INFORMATION TABLE

| Device code | VS- | 32 | С | т | Q | 030 | -M3 |
|-------------|---|-----------------------------------|--------------------------|---|----|---------|--------------------|
| | 1 | 2 | 3 | 4 | 5 | 6 | 7 |
| | 1 · · · · · · · · · · · · · · · · · · · | · Cur · Circ · C = · Pac | rent ratii cuit confi | niconduc ng (30 A guratior n cathoo | n: | oduct | |
| | 5 - 6 - 7 - | - Volt - Env | age rati ironmer | " series ngs —— ital digit jen-free, | | complia | 025 = 2 030 = 3 |

| ORDERING INFORMATION (Example) | | | | | | |
|--------------------------------|---------------|--------------------------|--|--|--|--|
| PREFERRED P/N | BASE QUANTITY | PACKAGING DESCRIPTION | | | | |
| VS-32CTQ025-M3 | 50 | Antistatic plastic tubes | | | | |
| VS-32CTQ030-M3 | 50 | Antistatic plastic tubes | | | | |

| LINKS TO RELATED DOCUMENTS | | | | | |
|-------------------------------------|--------------------------|--|--|--|--|
| Dimensions www.vishay.com/doc?96154 | | | | | |
| Part marking information | www.vishay.com/doc?95028 | | | | |



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